



isc Silicon NPN RF Transistor

DESCRIPTION

- Low Noise Figure, High Gain, and High Current Capability Achieve a Very Wide Dynamic Range and Excellent Linearity.
- · Low Noise and High Gain

NF = 1.2 dB TYP. @f = 1.0 GHz

Ga = 12 dB TYP. @f = 1.0 GHz

 Minimum Lot-to-Lot variations for robust device performance and reliable operation

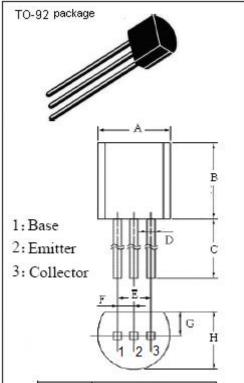


APPLICATIONS

 Designed for use in low-noise and small signal amplifiers from VHF ~ UHF band.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	20	V
Vceo	Collector-Emitter Voltage	10	V
V _{EBO}	Emitter-Base Voltage	1.5	V
lc	Collector Current-Continuous	65	mA
Pc	Collector Power Dissipation @T _C =25°C	0.6	W
TJ	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$



	mm		
DIM	MIN	MAX	
A	4.33	4.83	
В	4.33	4.83	
С	14.0	15.0	
D	0.36	0.56	
Е	2.5	54	
F	1.27		
G	0. 92	1. 12	
Н	3.40	3.60	



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ELECTRICAL CHARACTERISTICS

 T_{C} =25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
Ісво	Collector Cutoff Current	V _{CB} = 10V; I _E = 0			1.0	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = 1V; I _C = 0			1.0	μА
h _{FE}	DC Current Gain	I _C = 20mA ; V _{CE} = 8V	50		250	
f _T	Current-Gain—Bandwidth Product	I _C = 20mA ; V _{CE} = 8V		8		GHz
C _{re}	Feed-Back Capacitance	I _E = 0 ; V _{CB} = 10V;f= 1.0MHz		0.4	0.9	pF
S _{21e} ²	Insertion Power Gain	I _C = 20mA ; V _{CE} = 8V;f= 1.0GHz	9	11		dB
MAG	Maximum Available Gain	I _C = 20mA ; V _{CE} = 8V;f= 1.0GHz		13		dB
NF	Noise Figure	I _C = 7mA ; V _{CE} = 8V;f= 1.0GHz		1.2	2.5	dB

♦ h_{FE} Classification

Class	К
Marking	К
h _{FE}	50-250

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